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FORM PTO-1449 Modified  APR 1 8 2002 E  List of Patents, and Publications	Sheet 1 of 1		
Cited by Application (Use several sheets if necessary)  U.S. Department of Commerce	Docket No. BTG-10002	Serial No. 09/137,084	TECH!
Patent and Trademark Office	Applicant Michael F. Stumborg,	et al.	101021
	Filing Date August 20, 1998		Group-2813

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	AC	4,692,993	Sep-87	Clark, et al	437	
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	AF	5,124,762		Childs, et al	357	1
	AG	5,225,031		Mckee, et al	357	1
	AH	5,248,633		Morar, et al	156	61
	AI	5,285,079		Tsukamoto, et al.	437	19
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	ВС	Chu et al., "Hetero	Chu et al., "Heteroepitaxial deposition of group IIa fluorides on gallium arsenide"  Mat Sci and Eng. B, BolB47 1997 pp224-243					
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